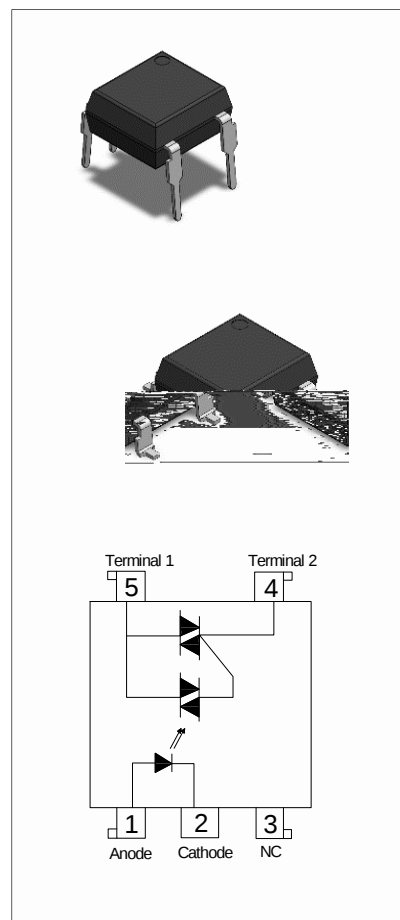


The products are 5-pin solid-state relay opto-couplers. The device combines an AlGaAs infrared emitting diode as the emitter which is optically coupled to a monolithic silicon random-phase photo triac to drive a power triac in a plastic DIP5 package with different lead forming options. The products are widely used in solenoid/valve controls, lighting controls, motor controls, temperature controls, static AC power switches, solid state relays, interfacing microprocessors to 265 V_{AC} peripherals.

High isolation 5000 Vrms
 DC input with triac output
 Operating temperature range - 40°C to 110 °C
 REACH & RoHS compliance
 HBM: H3B; MM: M4; CDM: C3
 CQC approved
 VDE approved
 UL approved



(Temperature=25°C)

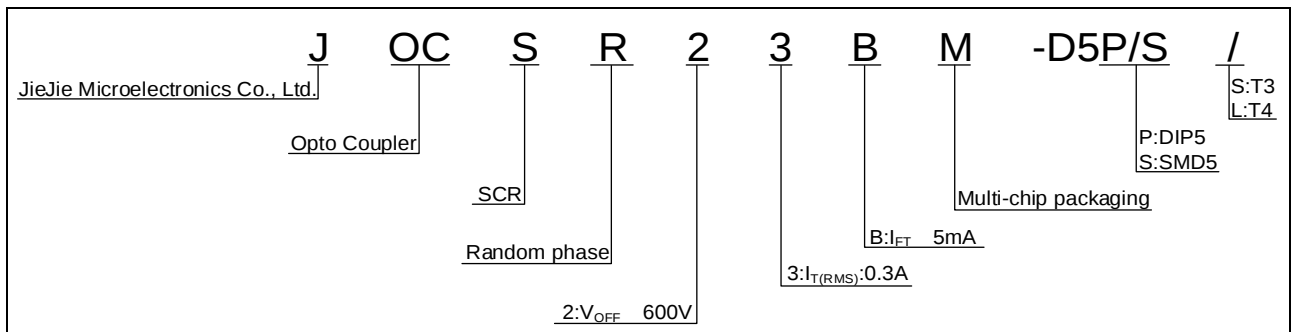
Input	Forward Current	I _F	50	mA
	Peak Forward Current	I _{FP}	1	A
	Reverse Voltage	V _R	6	V
	Power Dissipation	P _D	75	mW
Output	Repetitive peak off-state voltage	V _{DRM}	600	V
	Repetitive peak reverse voltage	V _{RRM}	600	V
	Critical rate of rise of on-state current	di/dt	100	A/μs
	On-state RMS Current (T _a ≤80 °C)	I _{T(RMS)}	0.3	A
	Non repetitive surge peak on-state current (full cycle , t _p =20ms)	I _{TSM}	3	A
	junction to case (AC)	R _{th(j-c)}	65	/W

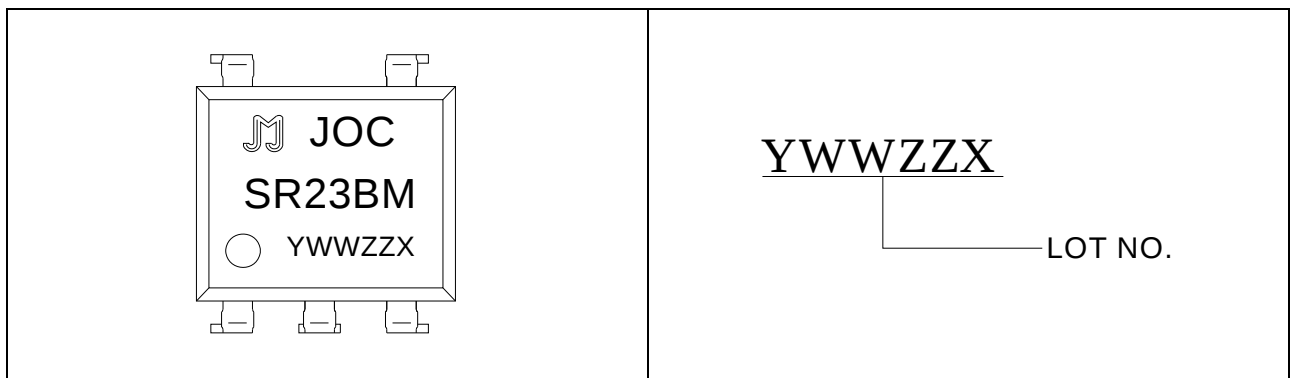


Isolation Voltage	V_{iso}	5000	Vrms
Operating Temperature	T_{opr}	-40~110	
Junction Temperature	T_j	125	
Storage Temperature	T_{stg}	-40~125	
Soldering Temperature	T_{sol}	260	
Peak pulse voltage ($T_j=25$; non-repetitive,off-state)	V_{pp}	3	kV

(Temperature=25°C)

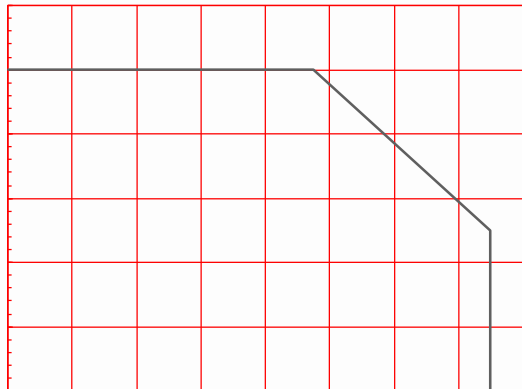
Input	Forward Voltage	V_F	$I_F=10mA$	-	1.2	1.5	V
	Reverse Current	I_R	$V_R=6V$	-	-	1	μA
Output	Peak Off-state Current, Either Direction	I_{DRM}	V_{DRM} / V_{RRM} $=600V, I_F=0$	-	-	5	μA
		I_{RRM}		-	-	5	
	Peak On-state Voltage, Either Direction	V_{TM}	$I_{TM}=I_{TM}$ Rated	-	-	1.5	V
	Critical Rate of Rise of Off-state voltage	dV/dt	$V_D=400V$, Gate Open $I_F=0$, $T_j=125$	1000	-	-	V/ μs
	Critical Rate of Rise of Commutating Voltage	$(dV/dt)_c$	$(dI/dt)_c$ $=1.5A/ms$, $T_j=125$	10	-	-	V/ μs
Transfer Characteristics	LED Trigger Current	I_{FT}	Terminal Voltage=6V $R_L=100\Omega$	-	-	5	mA
	Holding Current	I_H	$V_D=6V$	-	-	25	mA
	Isolation Resistance	R_{ISO}	DC500V 40~60%R.H.	10^{12}	10^{14}	-	Ω
	Response Time	t_{on}	$V_D=6V$, $R_L=100\Omega$, $I_F=20mA$	-	20	100	μs



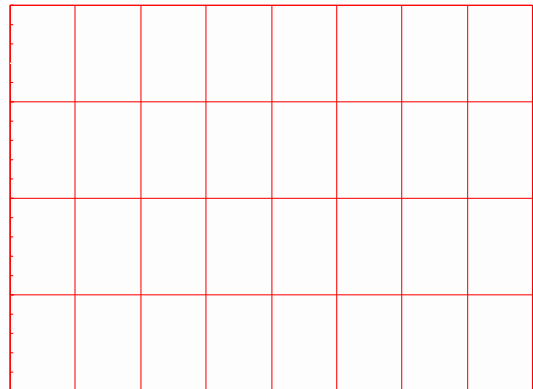




Max. Allowable LED Forward Current vs.
Ambient Temperature

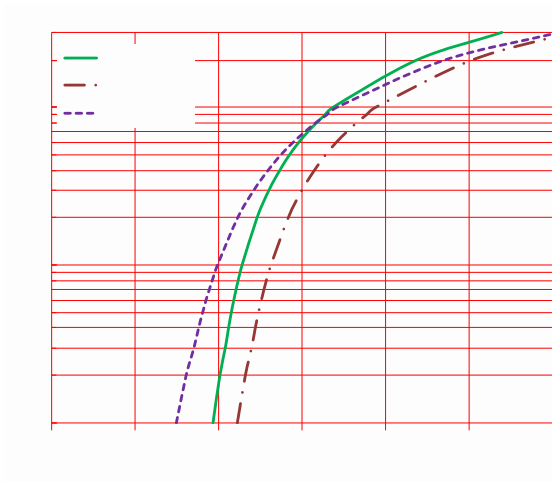


On-state Terminal Current vs. Ambient
Temperature

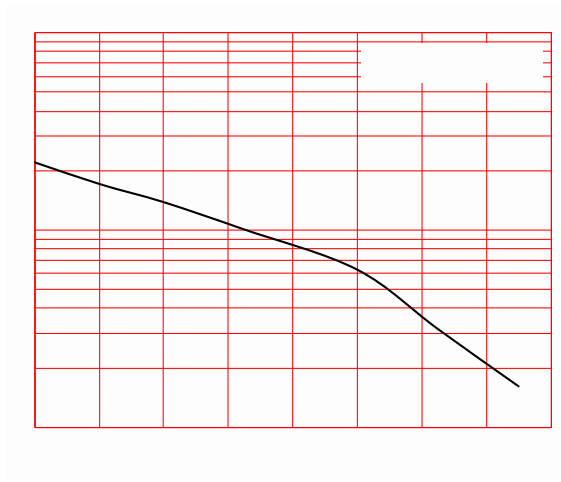




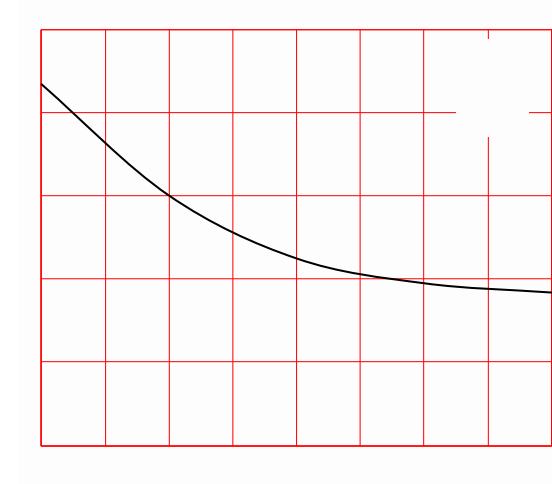
On-state characteristics



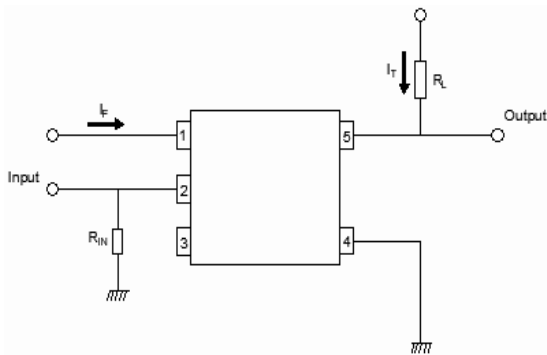
Normalized Holding Current vs. Ambient Temperature



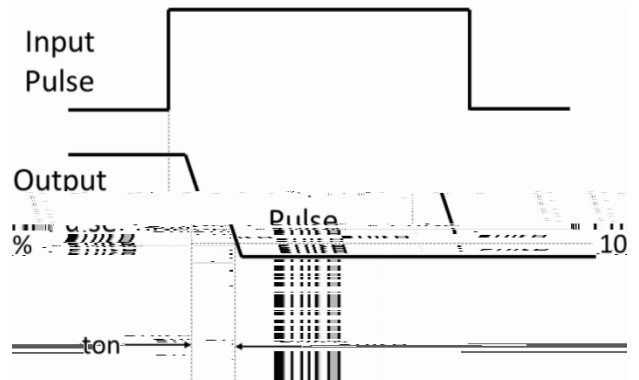
Turn On Time vs. Forward Current



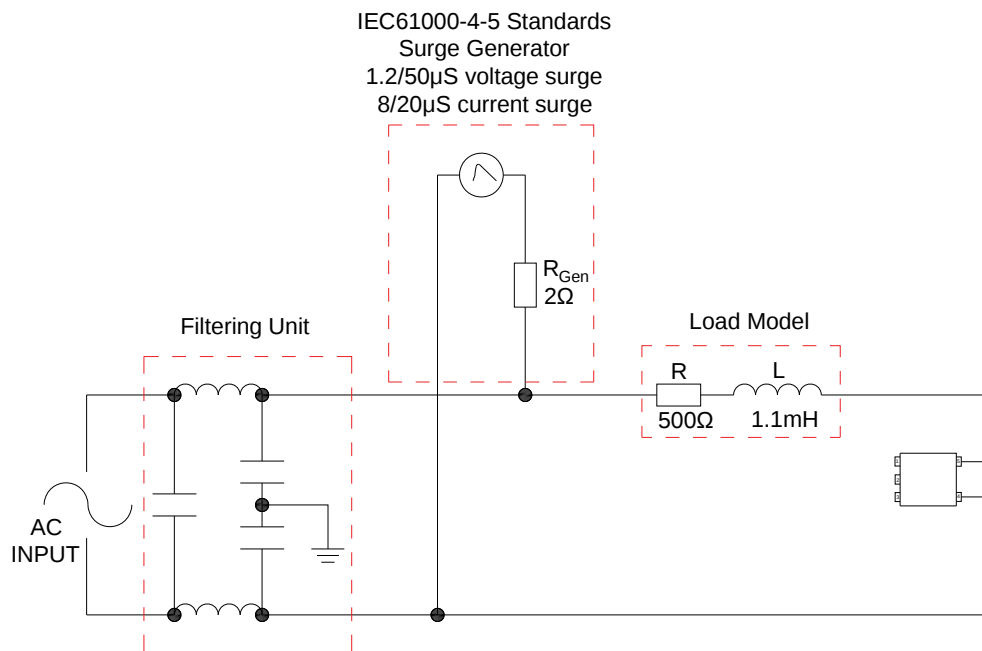
Test Circuits of Turn On Time

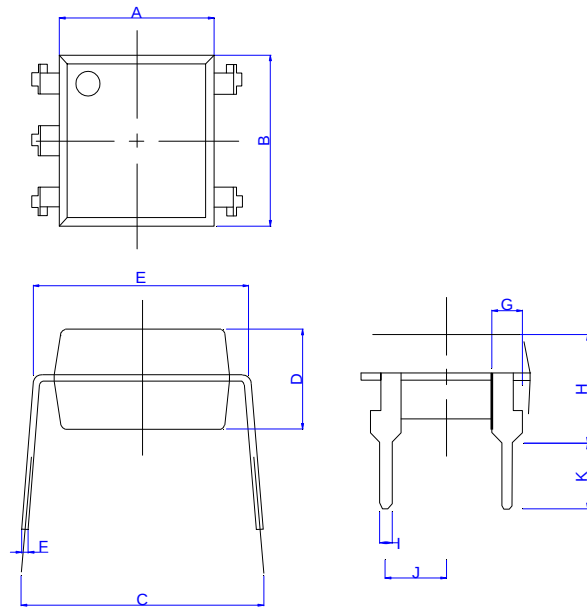


Waveforms of Turn On Time

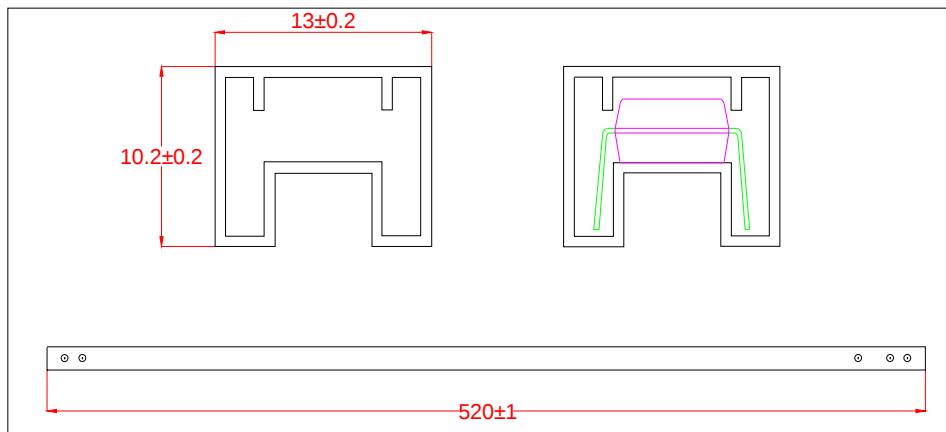
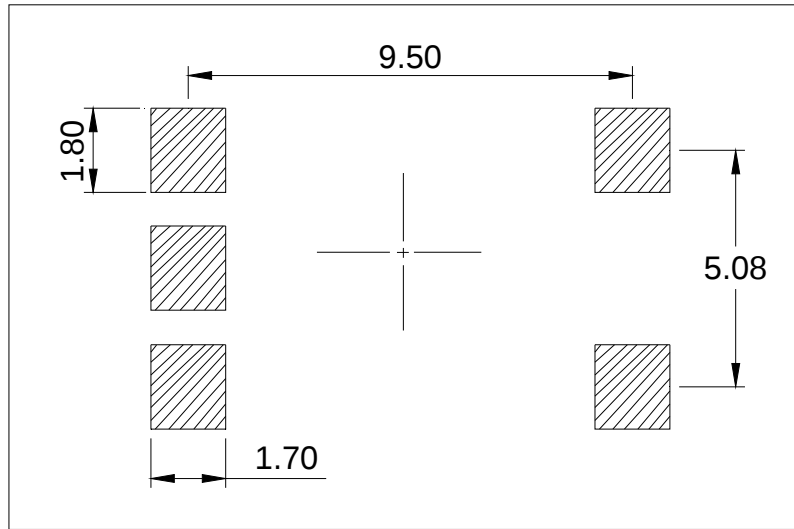


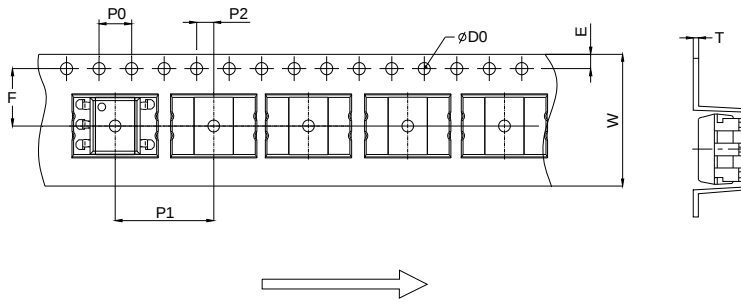
Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



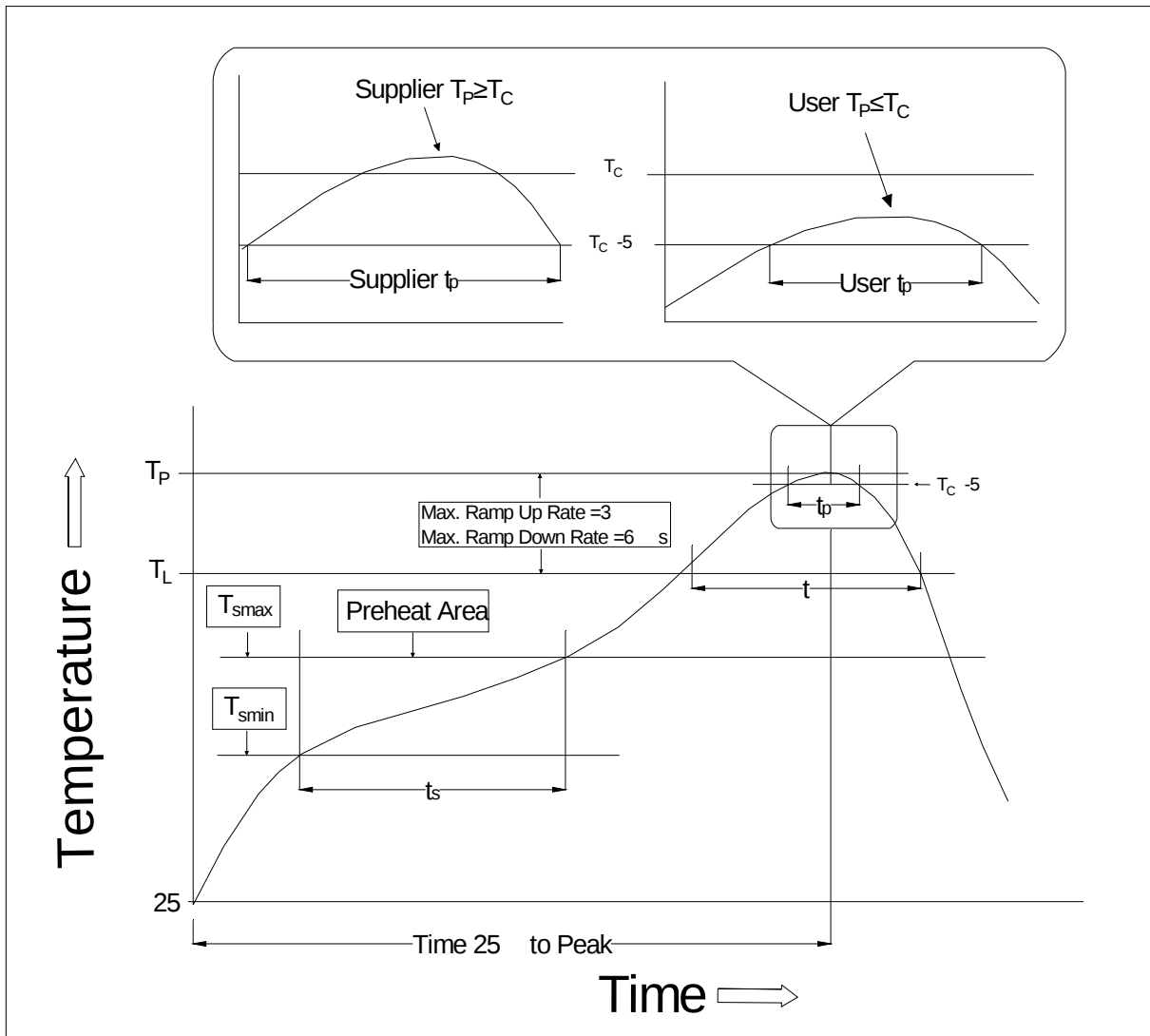


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	6.20		6.60	0.244		0.260
B	6.92		7.32	0.272		0.288
C	7.15		8.95	0.281		0.352
D	3.20		3.60	0.126		0.142
E	7.32		7.92	0.288		0.312
F						
G	1.15		1.35	0.045		0.053
H	3.90		4.50	0.154		0.177
I						
J						
K						

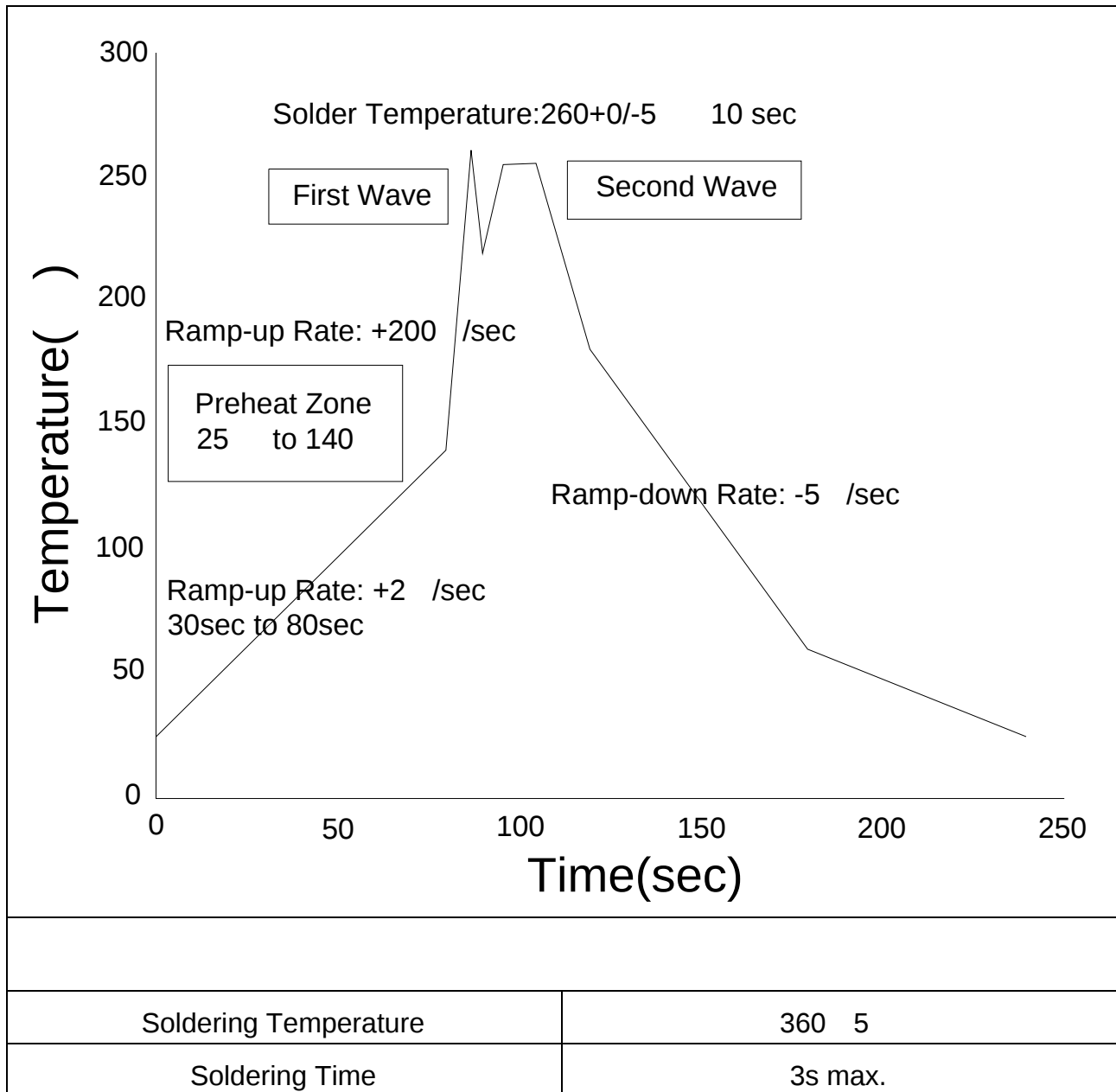




Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
D0		1.50	1.60		0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	11.90	12.00	12.10	0.469	0.472	0.476
P2	1.90	2.00	2.10	0.075	0.079	0.083
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
T	0.35	0.40	0.45	0.014	0.016	0.018
W	15.70	16.00	16.30	0.618	0.630	0.642



Temperature Min. (Tsmin)	150
Temperature Max. (Tsmax)	200
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (tL to tP)	3 /second max.
Liquidus Temperature (TL)	217
Time (tL) Maintained Above (TL)	60-120 seconds
Peak Body Package Temperature	260 +0 /-5
Time (tP) within 5 of 260	10 seconds
Ramp-down Rate (TP to TL)	6 /second max.





Note:

1. Reflow soldering is recommended at the temperatures and times shown, no more than three times.
2. Avoid direct contact between the epoxy body and any tools or surfaces exceeding its maximum storage temperature.
3. Application of pressure on the epoxy body